Charge transport, interfacial interactions and synergistic mechanism in BiNbO₄/MWO₄ (M = Zn and Cd) heterostructure for hydrogen production: insights from a DFT+*U* study

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Fig. S1. Calculated unfolded band structure of (a) $MoS_2(001)$, (b) $WS_2(001)$, (c) MoS_2/m -BiVO₄(010) and (d) WS_2/m -BiVO₄(010) within the hybrid HSE06 functional. The Fermi level is set to zero as dashed horizontal black line.



Fig. S2 GGA+*U* calculated PDOS of (a) $ZnWO_4(010)$ surface, (b) CdWO_4(010) surface, (c) BiNbO_4(010) surface, (d) BiNbO_4/ZnWO_4(010) heterostructure and (e) BiNbO_4/CdWO_4(010) heterostructure. The Fermi level is set to zero eV as a black dashed line.